EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2675	257/e27.098-e27.101. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/02/17 11:36
L2	228	257/e27.077.cdls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/02/17 11:58
L3	2032	257/288.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/02/17 12:08
L4	1898	257/401.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/02/17 12:25
L5	0	((mos or metal adj oxide adj semiconductor) and load adj capacitance and soft adj error and impurity adj concentration and well and diffusion). clm.	USPAT	OR	ON	2008/02/17 12:42
L6	0	((mos or metal adj oxide adj semiconductor) and load and soft adj error and impurity adj concentration and well and diffusion). clm.	USPAT	OR	ON	2008/02/17 12:42
L7	1	((mos or metal adj oxide adj semiconductor) and load and soft adj error and impurity adj concentration and well and diffusion). clm.	US-PGPUB; USPAT	OR	ON	2008/02/17 12:43

2/17/08 12:43:49 PM

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